TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSVI)

2SK3568

Switching Regulator Applications

• Low drain-source ON resistance: RDS (ON) = 0.4 Ω (typ.)

• High forward transfer admittance: $|Y_{fs}| = 8.5S$ (typ.)

• Low leakage current: IDSS = 100 μ A (VDS = 500 V)

• Enhancement mode: $V_{th} = 2.0 \sim 4.0 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA})$

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	500	V	
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	500	V	
Gate-source voltage		V _{GSS}	±30	V	
	DC (Note 1)	ID	12	А	
Drain current	Pulse (t = 1 ms) (Note 1)	I _{DP}	48		
Drain power dissipati	on (Tc = 25°C)	P _D	40	W	
Single pulse avalanche energy (Note 2)		E _{AS}	364	mJ	
Avalanche current		I _{AR}	12	Α	
Repetitive avalanche energy (Note 3)		E _{AR}	4	mJ	
Channel temperature	;	T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Unit: mm \$\frac{0.59 \to 0.15}{0.69 \to 0.15}\$ 1.14\to 0.15 \$\frac{0.69 \to 0.15}{0.69 \to 0.15}\$ 1. Gate 2: Drain 3: Source JEDEC JETA SC-67 TOSHIBA 2.7\to 0.2 2.

Weight: 1.7 g (typ.)

Thermal Characteristics

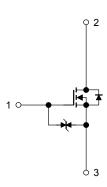
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	3.125	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{Ch} = 25°C(initial), L = 4.3 mH, I_{AR} = 12 A, R_G = 25 Ω

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.





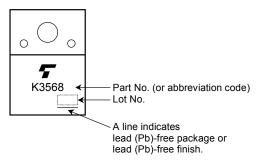
Electrical Characteristics (Ta = 25°C)

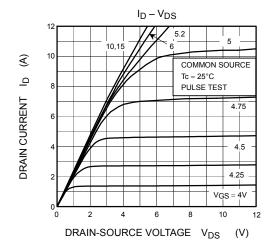
Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Gate-source brea	akdown voltage	V (BR) GSS	$I_G = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$	±30	_	_	V
Drain cut-off curr	ent	I _{DSS}	V _{DS} = 500 V, V _{GS} = 0 V	_	_	100	μА
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 10$ mA, $V_{GS} = 0$ V	500	_	_	V
Gate threshold v	oltage	V _{th}	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$	2.0	_	4.0	V
Drain-source ON	resistance	R _{DS (ON)}	V _{GS} = 10 V, I _D = 6 A	_	0.4	0.52	Ω
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 6 A	3.5	8.5	_	S
Input capacitance		C _{iss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	1500	_	pF
Reverse transfer capacitance		C _{rss}		_	15	_	
Output capacitance		C _{oss}]	_	180	_	
Switching time	Rise time	t _r	V_{GS} $V_{DD} \simeq 200 \text{ V}$ $V_{DD} \simeq 200 \text{ V}$	_	22	_	
	Turn-on time	t _{on}		_	50	_	
	Fall time	t _f		_	36	_	ns
	Turn-off time	t _{off}	Duty \leq 1%, $t_W = 10 \mu s$	_	170	_	
Total gate charge		Qg		_	42	_	
Gate-source charge		Q _{gs}	$V_{DD} \simeq 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 12 \text{ A}$	_	23	_	nC
Gate-drain charge		Q _{gd}]	_	19	_	

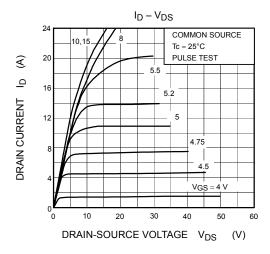
Source-Drain Ratings and Characteristics (Ta = 25°C)

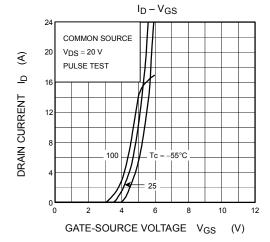
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	12	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	48	Α
Forward voltage (diode)	V _{DSF}	$I_{DR} = 12 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 12 \text{ A}, V_{GS} = 0 \text{ V},$	_	1200	_	ns
Reverse recovery charge	Q _{rr}	dI _{DR} /dt = 100 A/μs	_	16	_	μС

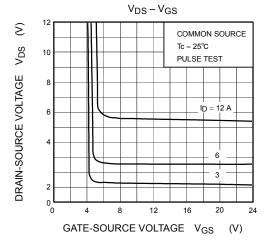
Marking

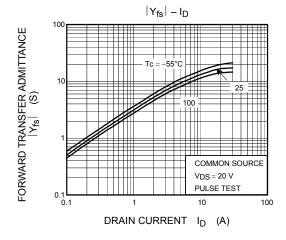


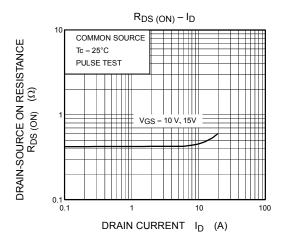


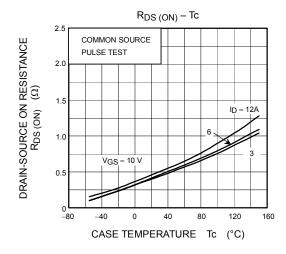


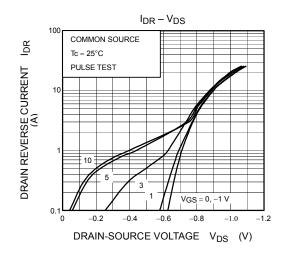


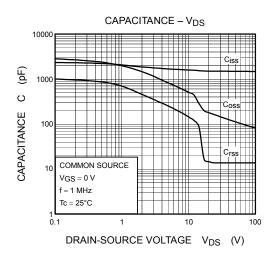


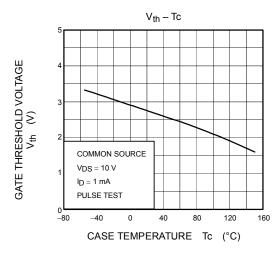


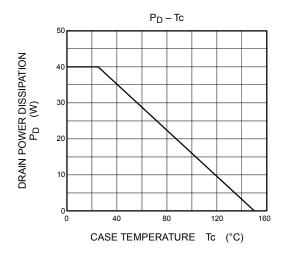


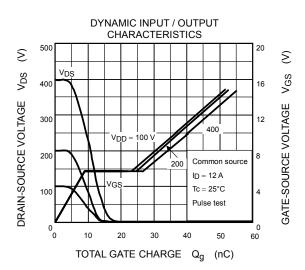


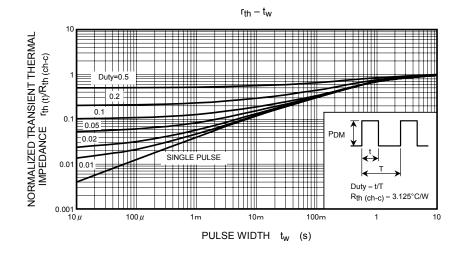


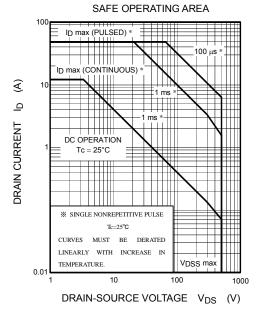


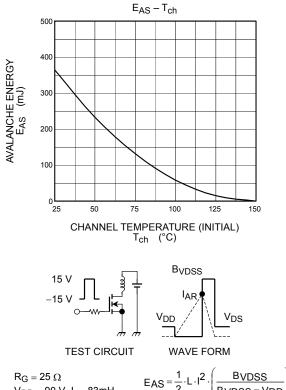












$$\begin{aligned} R_G &= 25~\Omega \\ V_{DD} &= 90~V,~L = 83\text{mH} \end{aligned} \qquad E_{AS} &= \frac{1}{2} \cdot L \cdot l^2 \cdot \left(\frac{BVDSS}{BVDSS} - V_{DD} \right) \end{aligned}$$

RESTRICTIONS ON PRODUCT USE

030619EAA

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which
 may result from its use. No license is granted by implication or otherwise under any patent or patent rights of
 TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Toshiba: 2SK3568(Q)